## 2SD1441

## Silicon NPN Triple-Diffused Junction Mesa Type

#### Horizontai Deflection Output

#### **■** Features

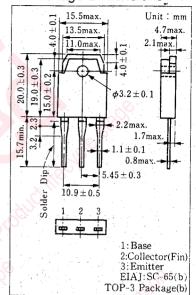
- Damper diode built-in
- High breakdown voltage and high reliability by glass passivation
- High speed switching
- Wide area of safety operation (ASO)

#### ■ Absolute Maximum Ratings (Tc=25°C)

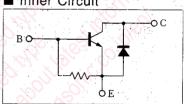
Item	Symbol	Value	Unit
Collector-base voltage	V <sub>CBO</sub>	1500	V
Collector-emitter voltage	V <sub>CES</sub>	1500	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	Ic	4	Α
Peak collector current	I <sub>CP</sub> *	15	A (C
Peak base current	$I_{BP}$	3.5	A A
Reverse peak base current	I <sub>BP</sub>	-2.5	A
Collector power dissipation $Tc = 25^{\circ}C$ $Ta = 25^{\circ}C$	B	70	101 (0)
	Pc	2.5	W
Junction temperature	$T_{j}$	130	CC C
Storage temperature	$T_{stg}$	$-55 \sim +130$	€ .CCC.

<sup>\*</sup> Non repetitive peak value

#### ■ Package Dimensions

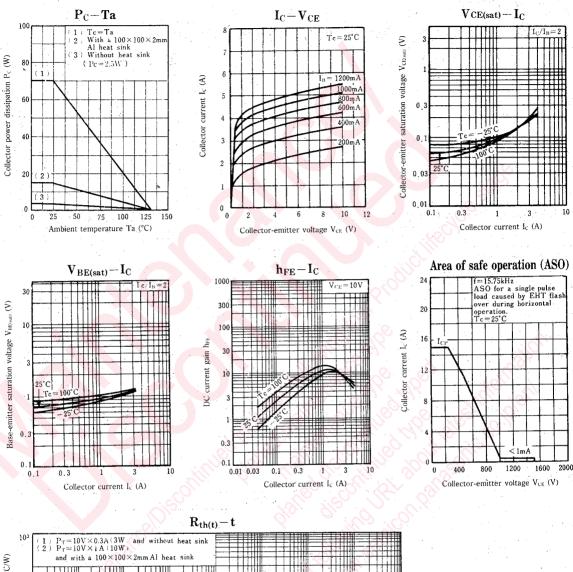


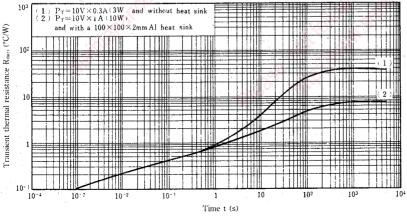
#### Inner Circuit



### ■ Electrical Characteristics (Tc=25°C)

ltem	Symbol	Condition		typ.	max.	Unit
Collector cutoff current	Ісво	$V_{CB} = 750 \text{ V}, I_E = 0$	0,		50	μΑ
		$V_{CB} = 1500 \text{ V}, I_E = 0$	,		1	mA
Emitter-base voltage	$V_{EBO}$	$I_E = 500 \text{ mA}, I_C = 0$	5			V
DC current gain	$h_{FE}$	$V_{CE} = 10 \text{ V}, I_{C} = 3A$	5		15	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 3 A, I_B = 1 A$			i	V
Base-emitter saturation voltage	VBE(sat)	$I_C = 3 \text{ A}, I_B = 1 \text{ A}$			1.5	V
Transition frequency	$f_{T}$	$V_{CE} = 10V$ , $I_C = 0.5A$ , $f = 0.5MHz$		2		MHz
Fall time	t <sub>f</sub>	$I_C = 3A$ , $I_{Bend} = 1A$			0.75	μ <sub>S</sub>
Storage time	$t_{ m stg}$	$L_{\text{leak}} = 5\mu H$	4		9	μς
Diode forward voltage	$V_{\rm F}$	$I_{C} = -4A, I_{B} = 0$		11.11.	-2.2	V





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